

# 2STA1943

## High power PNP epitaxial planar bipolar transistor

### Features

- High breakdown voltage V<sub>CEO</sub> > -230V
- Complementary to 2STC5200
- Fast-switching speed
- Typical f<sub>T</sub> = 30 MHz

### Application

Audio power amplifier

### Description

This device is a NPN transistor manufactured using new BiT-LA (Bipolar Transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

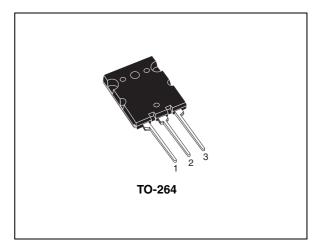
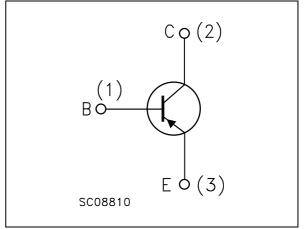


Figure 1. Internal schematic diagram



#### Table 1. Device summary

Order code	Marking	Package	Packaging
2STA1943	2STA1943	TO-264	Tube

## 1 Electrical ratings

Table 2.	Absolute	maximum	ratings
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Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage ( $I_E = 0$ )	-230	V
V <sub>CEO</sub>	Collector-emitter voltage ( $I_B = 0$ )	-230	V
V <sub>EBO</sub>	Emitter-base voltage $(I_C = 0)$	-5	V
۱ <sub>C</sub>	Collector current	-15	А
I <sub>CM</sub>	Collector peak current	-30	A
P <sub>tot</sub>	Total dissipation at $T_C = 25^{\circ}C$	150	W
T <sub>stg</sub>	Storage temperature	-55 to 150	°C
Т <sub>Ј</sub>	Operating junction temperature	150	°C

#### Table 3.Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJ-case</sub>	Thermal resistance junction-case Max	0.83	°C/W



## 2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$ 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = -230 V			-5	μA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = -5 V			-5	μA
V <sub>(BR)CEO</sub> <sup>(1)</sup>	Collector-emitter breakdown voltage ( $I_B = 0$ )	I <sub>C</sub> = -50 mA	-230			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage (I <sub>E</sub> = 0)	Ι <sub>C</sub> = -100 μΑ	-230			V
V <sub>(BR)EBO</sub> <sup>(1)</sup>	Emitter-base breakdown voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = -1 mA	-5			V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	I <sub>C</sub> = -8 A I <sub>B</sub> = -800 mA			-3	v
$V_{BE}$	Base-emitter voltage	$I_{C} = -7 A$ $V_{CE} = -5 V$			-1.5	v
h <sub>FE</sub>	DC current gain	$I_{C} = -1 A$ $V_{CE} = -5 V$ $I_{C} = -7 A$ $V_{CE} = -5 V$	80 35		160	
t <sub>on</sub> t <sub>s</sub> t <sub>f</sub>	Resistive load Turn-on time Storage time Fall time	$V_{CC} = -60 V I_{C} = -5A$ $I_{B1} = -I_{B2} = -0.5 A$		0.24 1.2 0.21		µs µs µs
f <sub>T</sub>	Transition frequency	$I_{C} = -1 A$ $V_{CE} = -5 V$		30		MHz
C <sub>CBO</sub>	Collector-base capacitance $(I_E = 0)$	V <sub>CB</sub> = -10 V f = 1 MHz		225		pF

	Table 4.	Electrical	characteristics
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1. Pulsed: pulse duration = 300  $\mu s,$  duty cycle  $\leq 1.5\%$ 



DG11570

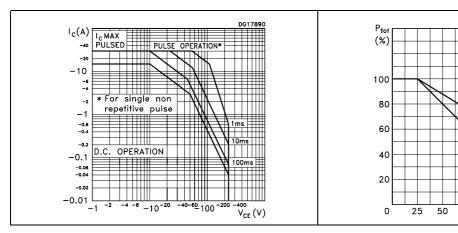
S/B

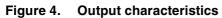
75 100 125 T<sub>case</sub>(°C)

### 2.1 Electrical characteristics (curves)

#### Figure 2. Safe operating area









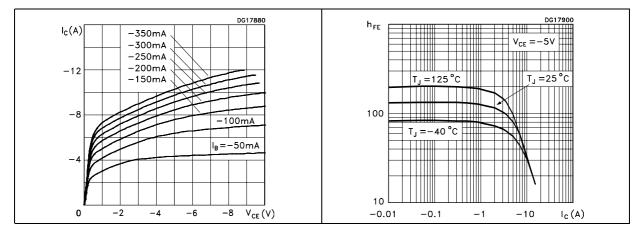
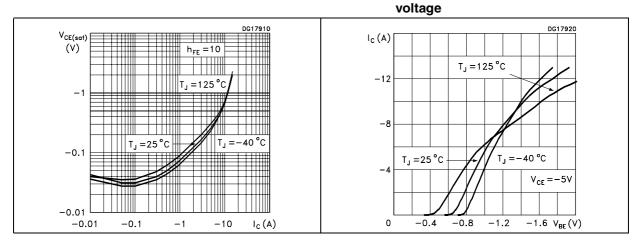
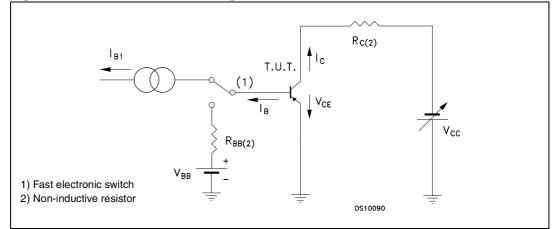


Figure 6. Collector-emitter saturation voltage Figure 7. Collector current vs base-emitter



### 2.2 Test circuit



#### Figure 8. Resistive load switching test circuit



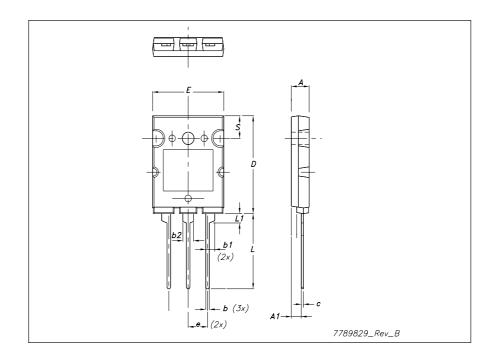
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



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	TO-264 Mechanical data		
Dim.		mm.	
<b>B</b>	Min.	Тур	Max.
А	4.80		5.20
A1	2.50		3.10
b	0.90	1.0	1.25
b1		2.5	
b2		2.8	
с	0.50	0.60	0.85
D	25.6		26.4
Е	19.80		20.20
е	5.15		5.75
L	19.50		20.50
L1	2.30		2.70
øР	3.55		3.65





## 4 Revision history

#### Table 5.Document revision history

Date	Revision	Changes	
18-Jun-2007	1	Initial release.	
12-Dec-2007	2	Document promoted from preliminary data to datasheet.	



57

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